

HIGH SPEED CMOS LOGIC IC ELM7SH08xB 2-input AND gate

<https://www.elm-tech.com>

■General description

ELM7SH08xB is CMOS 2-input AND gate which is suitable for battery-operated devices because of its low voltage and ultra high speed operation. The low power consumption contributes to longer battery life, which allows long time operation of devices. The internal circuit which provides high noise immunity and stable output is composed of 4 stages, including buffered output. All input pins have an input tolerant circuit configuration. In other words, there is no diode on the positive side (forward from input to Vdd), so it ensures that 0 to 5.5 V can be applied to the input pins without regard to the supply voltage.

■Features

- Same electrical characteristic and high speed operation as 74VHC series
- Low consumption current : $I_{dd}=1.0\mu A$ (Max.)(Top=25°C)
- Wide power voltage range : 1.65V to 5.5V
- Wide input voltage range : $V_{ih}=5.5V$ (Max.)($V_{dd}=0$ to 5.5V)
- High speed : $T_{pd}=2.8ns$ (Typ.)($V_{dd}=5.0V$)
- Small package : SOT-25, SC-70-5(SOT-353)
- Same function and pin configuration as ELM7SxB

■Application

- Cell phones
- Digital cameras
- Portable electrical appliances like PDA, etc.
- Computers and peripherals
- Digital electrical appliances like LCD TV sets, DVD recorders/players, STB, etc.
- Modification inside print board, adjustment of timing, solution to noise
- Power voltage change from 5V to 3V (Input tolerant)

■Selection guide

ELM7SH08xBEL

Symbol	Function	08: 2-input AND gate
a	Function	08: 2-input AND gate
b	Package	M: SOT-25 T : SC-70-5(SOT-353)
c	Product version	B
d	Taping direction	EL: Refer to PKG file

ELM7SH 0 8 x B EL
↑ ↑ ↑ ↑
a b c d

■Maximum absolute ratings

Parameter	Symbol	Limit	Unit
Power supply voltage	V_{dd}	-0.5 to +6.0	V
Input voltage	V_{in}	-0.5 to +6.0	V
Output voltage	V_{out}	-0.5 to $V_{dd}+0.5$	V
Input protection diode current	I_{ik}	-20	mA
Output parasitic diode current	I_{ok}	± 20	mA
Output current	I_{out}	± 25	mA
VDD/GND current	I_{dd}, I_{gnd}	± 50	mA
Power dissipation	P_d	150	mW
Storage temperature	T_{stg}	-65 to +150	°C

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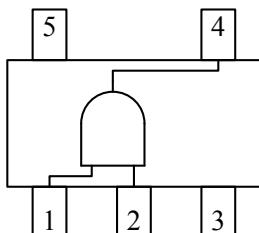
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■Suggested operating condition

Parameter	Symbol	Limit		Unit
Power voltage	Vdd	1.65 to 5.5		V
Input voltage	Vin	0 to 5.5		V
Output voltage	Vout	0 to Vdd		V
Operating temperature	Top	-40 to +85		°C
High-input down-time	tr, tf	Vdd=1.8±0.15V Vdd=2.5±0.2V Vdd=3.3±0.3V Vdd=5.0±0.5V	0 to 300 0 to 200 0 to 200 0 to 100	ns

■Pin configuration

TOP VIEW



Pin No.	Pin name
1	INB
2	INA
3	GND
4	OUTX
5	VDD

Input	Output
INA	INB
Low	Low
Low	High
High	Low
High	High

■DC electrical characteristics

Parameter	Sym.	Vdd	Top=25°C		Top=-40 to +85°C		Unit	Condition
			Min.	Max.	Min.	Max.		
Input voltage	Vih	1.65	1.23	-	1.23	-	V	
		2.0	1.50	-	1.50	-		
		3.0	2.10	-	2.10	-		
		5.5	3.85	-	3.85	-		
	Vil	1.65	-	0.42	-	0.42	V	
		2.0	-	0.50	-	0.50		
		3.0	-	0.90	-	0.90		
		5.5	-	1.65	-	1.65		
Output voltage	Voh	1.65	1.55	-	1.55	-	V	Vin=Vih Ioh=-50μA
		2.0	1.90	-	1.90	-		
		3.0	2.90	-	2.90	-		
		4.5	4.40	-	4.40	-		
		3.0	2.58	-	2.48	-		
		4.5	3.94	-	3.80	-		
	Vol	1.65	-	0.10	-	0.10	V	Vin=Vil or Vih Iol=50μA
		2.0	-	0.10	-	0.10		
		3.0	-	0.10	-	0.10		
		4.5	-	0.10	-	0.10		
		3.0	-	0.36	-	0.44		
		4.5	-	0.36	-	0.44		
Input current	Iin	5.5	-0.1	0.1	-1.0	1.0	μA	Vin=Vdd or GND
Static current	Idd	5.5	-	1.0	-	10.0	μA	Vin=Vdd or GND

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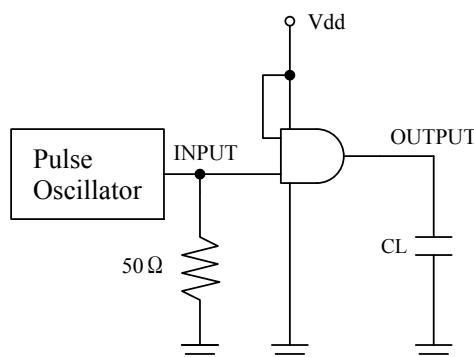
■AC electrical characteristics

tr=tf=3ns

Parameter	Sym.	Vdd	CL	Top=25°C			Top=-40 to +85°C		Unit	Condition
				Min.	Typ.	Max.	Min.	Max.		
Propagation delay-time	tPLH	1.8 ± 0.15	15	-	12.8	22.7	1.0	25.0	ns	Refer to test circuit
	tPHL			-	12.8	22.7	1.0	25.0		
	tPLH	1.8 ± 0.15	50	-	19.4	32.8	1.0	38.5		
	tPHL			-	19.4	32.8	1.0	38.5		
	tPLH	2.5 ± 0.2	15	-	7.9	13.8	1.0	16.0		
	tPHL			-	7.9	13.8	1.0	16.0		
	tPLH	2.5 ± 0.2	50	-	10.5	17.3	1.0	20.0		
	tPHL			-	10.5	17.3	1.0	20.0		
	tPLH	3.3±0.3	15	-	3.7	8.8	1.0	10.5		
	tPHL			-	3.2	8.8	1.0	10.5		
	tPLH	3.3±0.3	50	-	5.2	12.3	1.0	14.0		
	tPHL			-	4.5	12.3	1.0	14.0		
	tPLH	5.0±0.5	15	-	2.8	5.9	1.0	7.0		
	tPHL			-	2.4	5.9	1.0	7.0		
	tPLH	5.0±0.5	50	-	3.7	7.9	1.0	9.0		
	tPHL			-	3.4	7.9	1.0	9.0		
Input capacity	Cin	5.0	-	-	4.0	10.0	-	10.0	pF	Vin=Vdd or GND
Equivalent inner capacity	Cpd	-	-	-	9.3	-	-	-	pF	f=1MHz

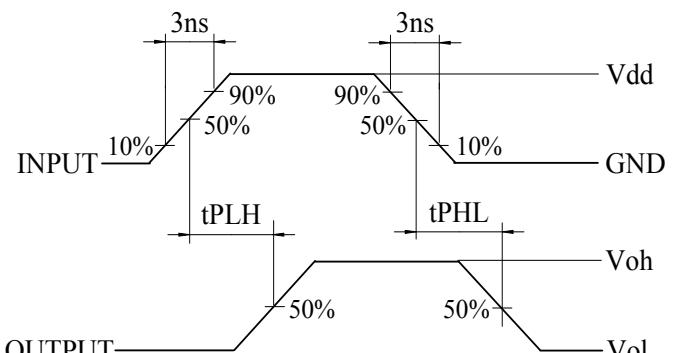
* Cpd is IC's inner equivalent capacity which is calculated from non-loaded operating current consumption referred to test circuit. Averaged operating current consumption at non load is calculated as following formula: $I_{dd(\text{opr})} = C_{pd} \cdot V_{dd} \cdot f_{in} + I_{dd}$

■Test circuit



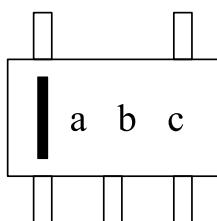
* Output should be opened when measuring current consumption.

■Measured wave pattern

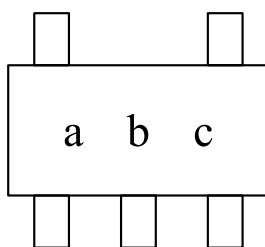


■Marking

SC-70-5



SOT-25



Sym.	Mark	Content
a	F	ELM7SH series
b	2	ELM7SH08xB
c	A to Z (except I, O, X)	Lot No.